

isc Silicon PNP Power Transistor

2SA1106

DESCRIPTION

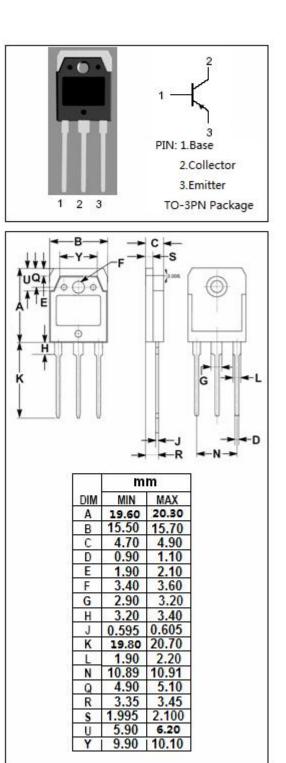
- Collector-Emitter Breakdown Voltage-V_{(BR)CEO}= -140V(Min)
- Good Linearity of h_{FE}
- High Power Dissipation
- Complement to Type 2SC2581
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

• Designed for audio and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

ABSOLUTE MAXIMUM RATINGS(Ta=25 C)							
SYMBOL	PARAMETER	VALUE	UNIT				
V _{CBO}	Collector-Base Voltage	-140	V				
V _{CEO}	Collector-Emitter Voltage	-140	V				
V _{EBO}	Emitter-Base Voltage	-6	V				
lc	Collector Current-Continuous	-10	A				
I _B	Base Current-Continuous	-4	A				
Pc	Collector Power Dissipation @ T _C =25℃	100	W				
TJ	Junction Temperature 150		°C				
T _{stg}	Storage Temperature Range	-55~150	°C				



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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -50mA; I _B = 0	-140			v
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -5A; I _B = -0.5A			-2.0	v
Ісво	Collector Cutoff Current	V _{CB} = -140V; I _E = 0			-100	μ Α
I _{EBO}	Emitter Cutoff Current	V _{EB} = -6V; I _C = 0			-100	μ Α
h _{FE}	DC Current Gain	Ic= -3A; V _{CE} = -4V	30			
f⊤	Current-Gain—Bandwidth Product	I _E = 0.5A; V _{CE} = -12V		20		MHz

Switching Times

tr	Rise Time		0.3	μ S
t _{stg}	Storage Time	I _C = -5A, R _L = 12 Ω , I _{B1} = -I _{B2} = -0.5A, V _{CC} = -60V	0.9	μs
t _f	Fall Time		0.2	μ S

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